

EE-606: Solid State Devices

Lecture 2: Geometry of Periodic Crystals

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Outline

- 1) **Volume & surface issues for BCC, FCC, Cubic lattices**
- 2) Important material systems
- 3) Miller indices
- 4) Conclusions

Reference: Vol. 6, Ch. 1 (pages 10-17)

Helpful software: Crystal Viewer in ABACUS tool at nanohub.org

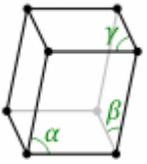
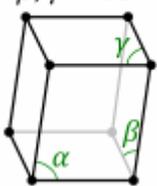
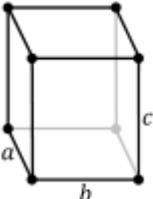
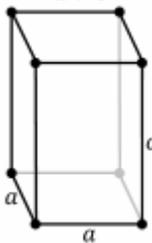
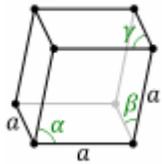
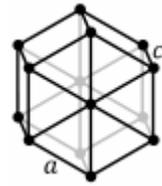
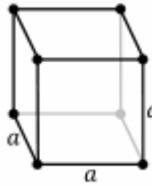
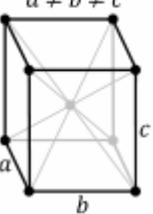
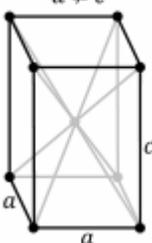
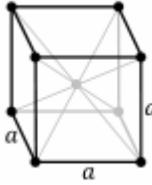
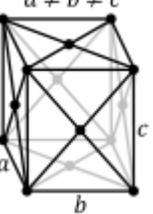
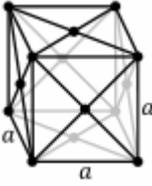
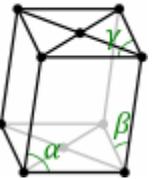
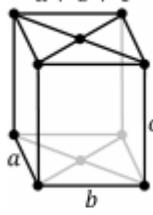
The story so far ...

1. We want to compute current in a material, $J=q n v$
2. Computing (n) and (v) requires knowledge of composition and periodicity of the material
3. If the atoms are arranged in a periodic array, then calculation of (n) and (v) will be easier.

Therefore, we are studying the symmetry of the unit cell, hoping that we will be able to identify them in various materials.

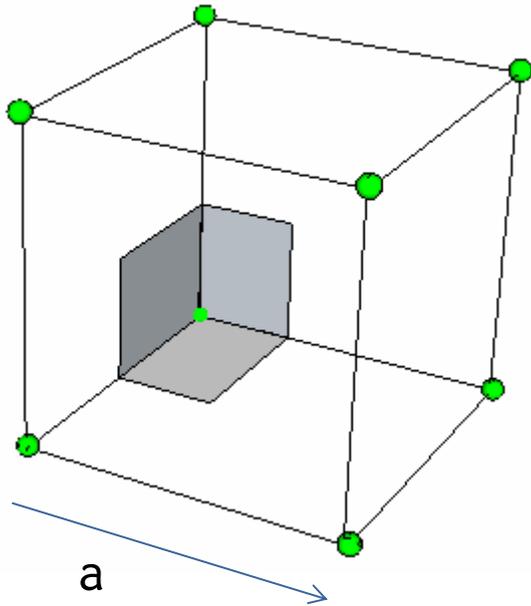
Important Bravais lattices

Polonium84

	Triclinic	Monoclini	Orthorhomb	Tetragonal	Rhombohedral	Hexagonal	Cubic
P	$\alpha, \beta, \gamma \neq 90^\circ$ 	ϵ $\alpha \neq 90^\circ$ $\beta, \gamma = 90^\circ$ 	ie $a \neq b \neq c$ 	$a \neq c$ 	$\alpha, \beta, \gamma \neq 90^\circ$ 	$a \neq c$ 	
I			$a \neq b \neq c$ 	$a \neq c$ 			
F			$a \neq b \neq c$ 				
C		$\alpha \neq 90^\circ$ $\beta, \gamma = 90^\circ$ 	$a \neq b \neq c$ 				



Cubic Lattice: Volume Issues

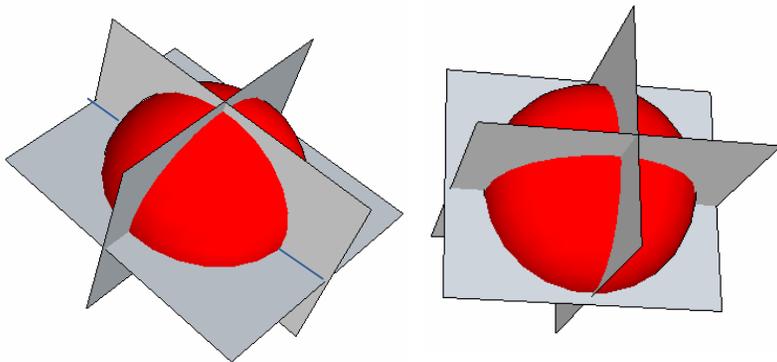


Points per cell

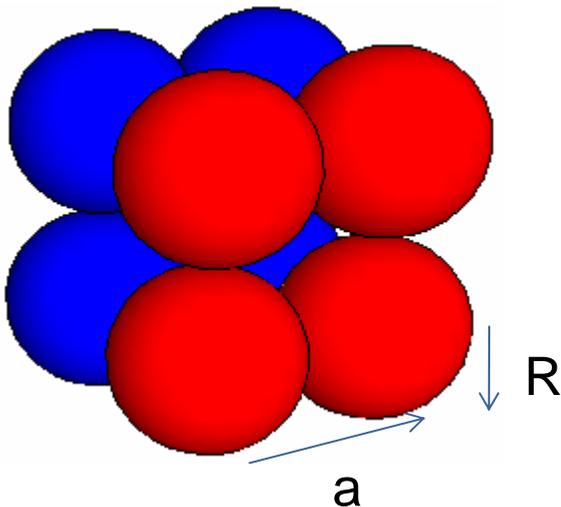
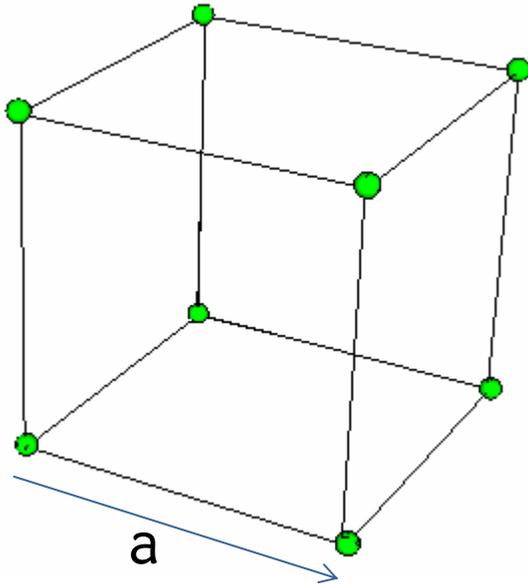
= $1/8$ points/corner \times 8 corners
= 1 Point/cell.
(depends on definition of cell)

Number density

= $(1/a^3)$ points/cm³.
(does not depend on cell definition)



Cubic Lattice: Volume Issues



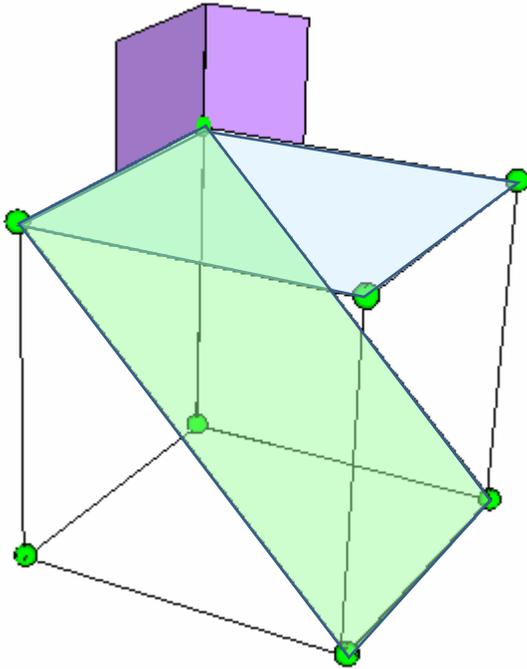
Packing density
= volume filled / total volume

$$R = a/2$$

$$P = (1/8) \times (4/3)\pi R^3 \times (8 \text{ corners}) / a^3$$
$$= \pi/6$$

(does not depend on cell definition)

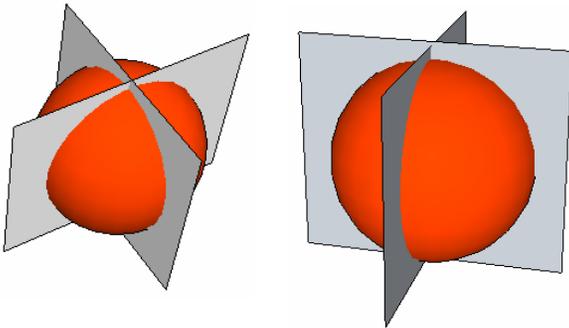
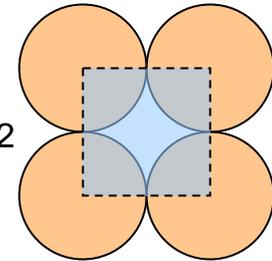
Cubic Lattice: Surface Issues



Areal Density

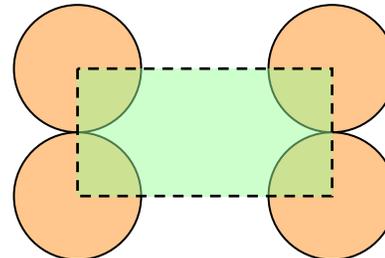
$$= (1/4 \text{ per corner}) \times (4 \text{ corners}) / a^2$$

$$= 1/a^2 \text{ cm}^{-2}$$

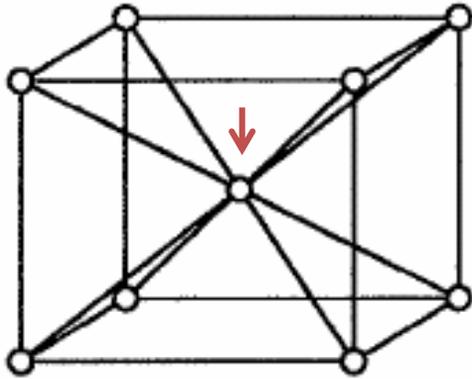


Areal density (face diagonal)

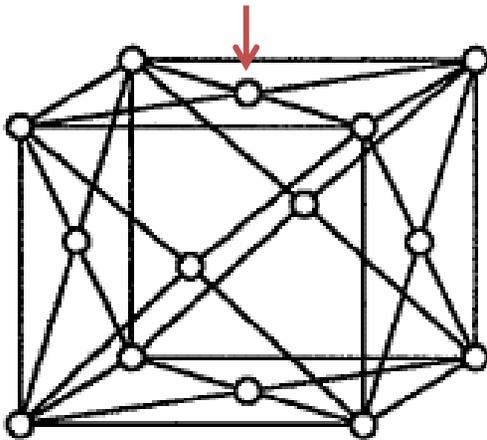
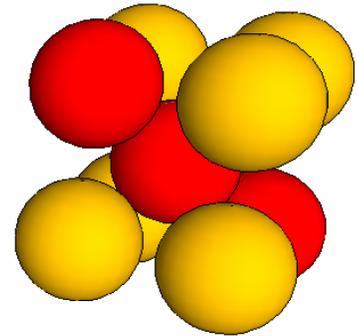
$$= (1/4 \text{ points/corner}) \times (4 \text{ corners}) / \sqrt{2}a^2 \text{ cm}^{-2}$$



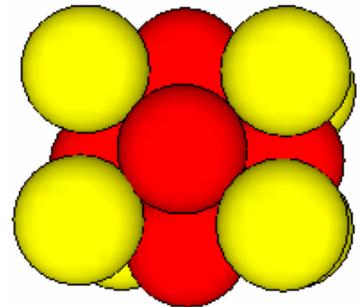
BCC and FCC lattices



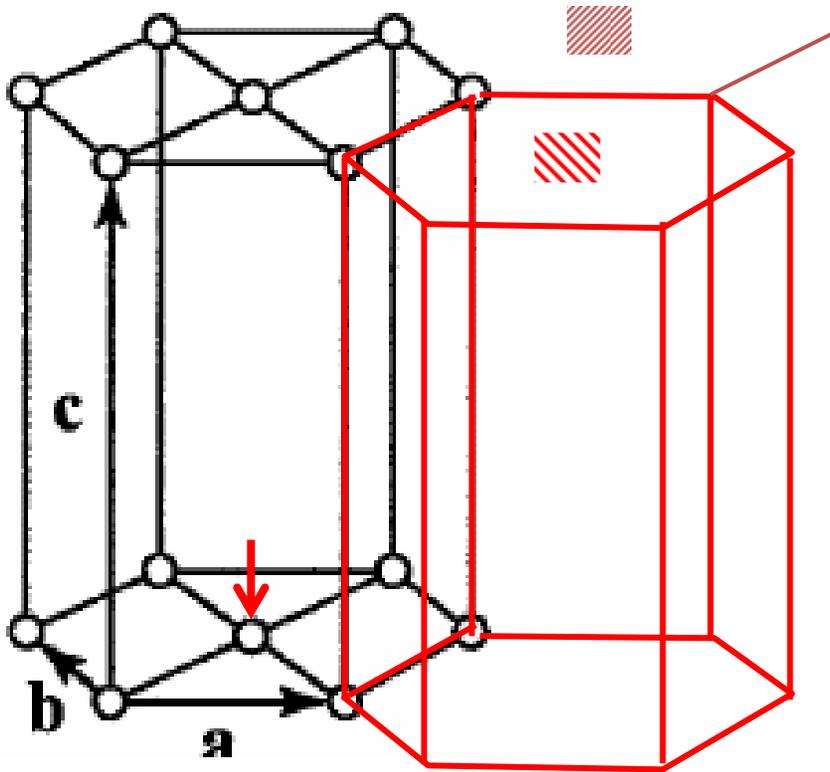
Points per cell
= $1/8 \times 8$ @corners
+ 1 @inside
= 2



Points per cell
= $1/8 \times 8$ @corners
+ $1/2 \times 6$ @faces
= 4

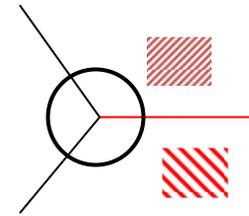


Hexagonal Closed-Packed



Points per cell

$$\frac{1}{2} \times 2 \text{ @faces} = 1$$



$$\frac{1}{2} \times \frac{1}{3} \times 12 \text{ @corners} = 2$$

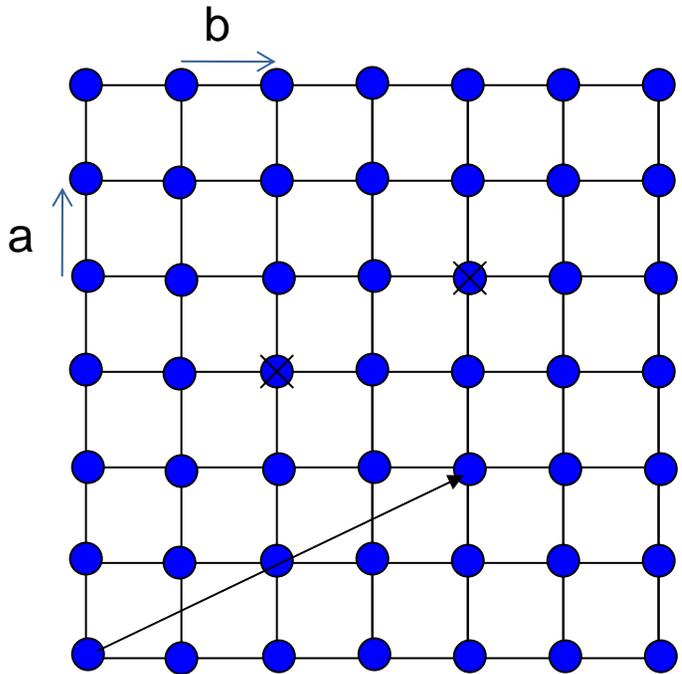
3 points/cell

Outline

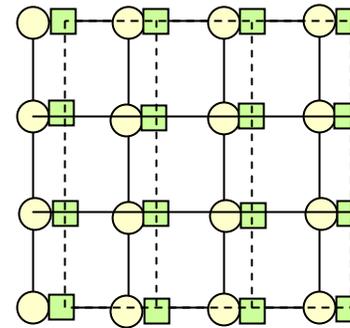
- 1) Volume & surface issues for BCC, FCC, Cubic lattices
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Geometry of Lattice Points

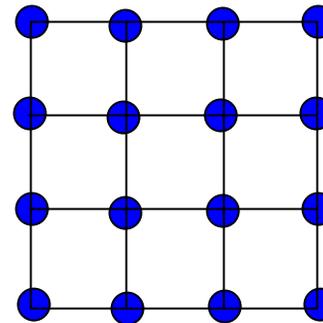
In a Bravais lattice, every point has the same environment as every other point (same number of neighbors, next neighbors, ...)



$$R = h \vec{a} + k \vec{b}$$



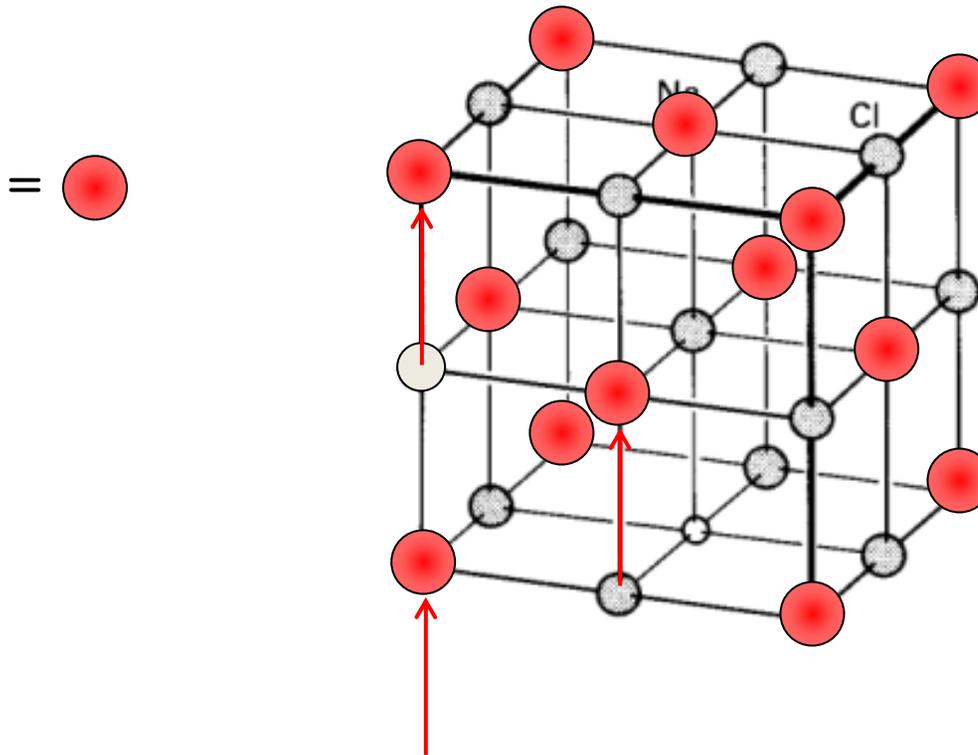
Non-Bravais lattice



Bravais lattice
with a basis

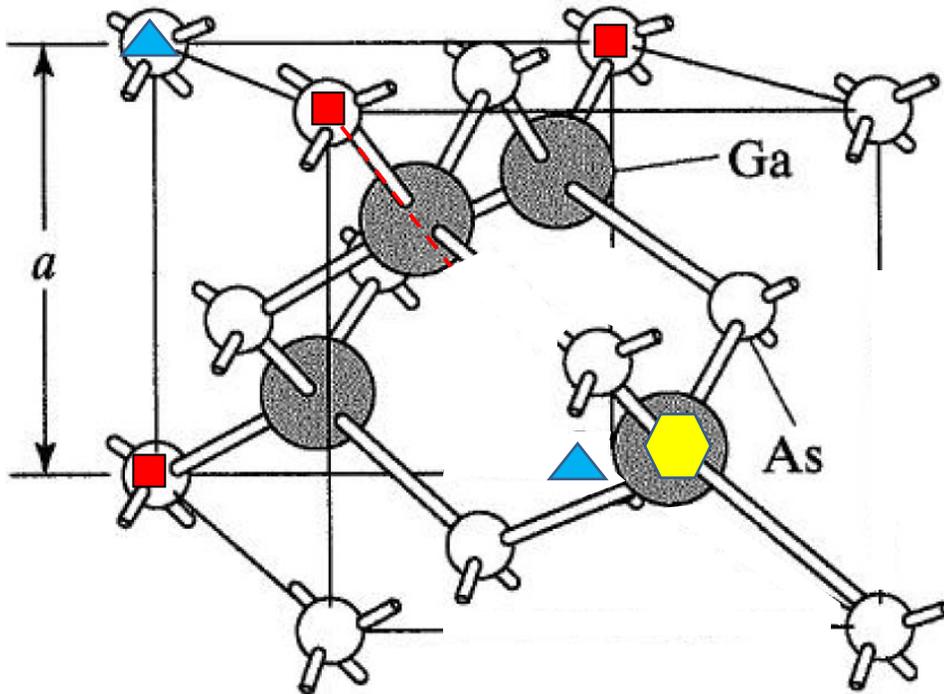


Rock-Salt as FCC lattice

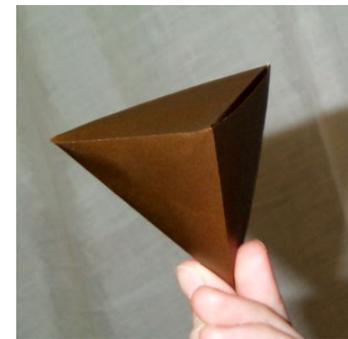


For more discussion, see Kittel and Ashcroft/Mermin

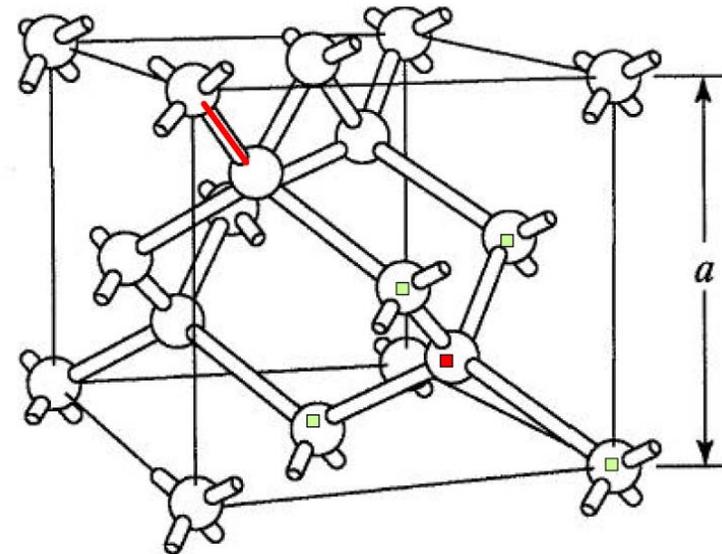
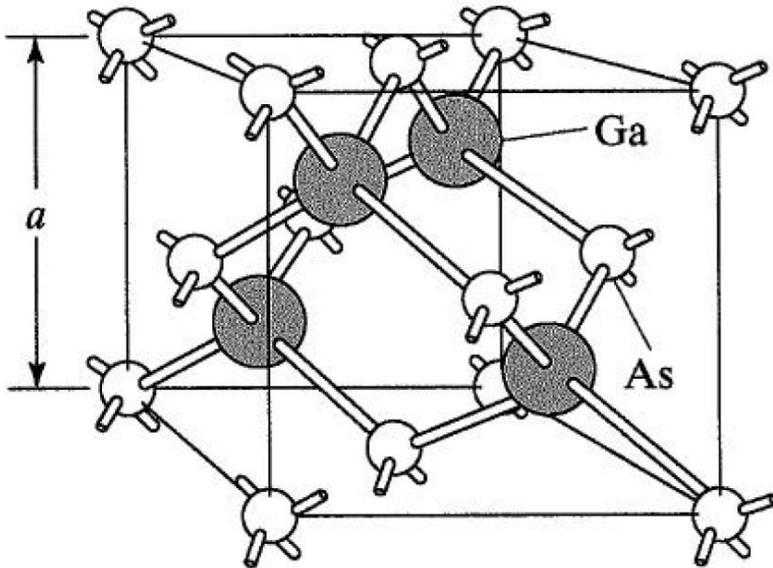
Zinc-Blende FCC Lattice for GaAs



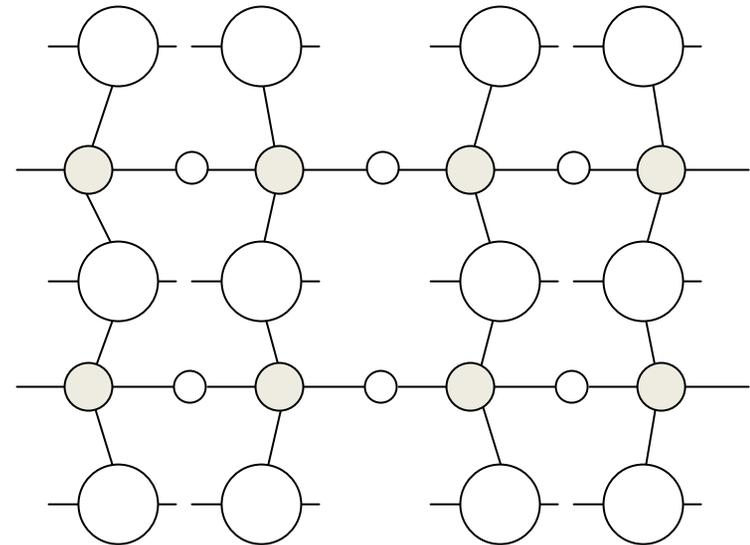
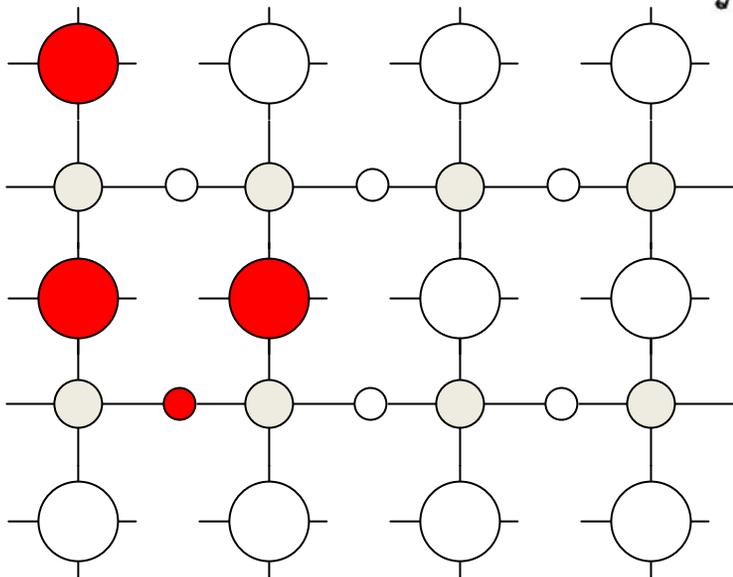
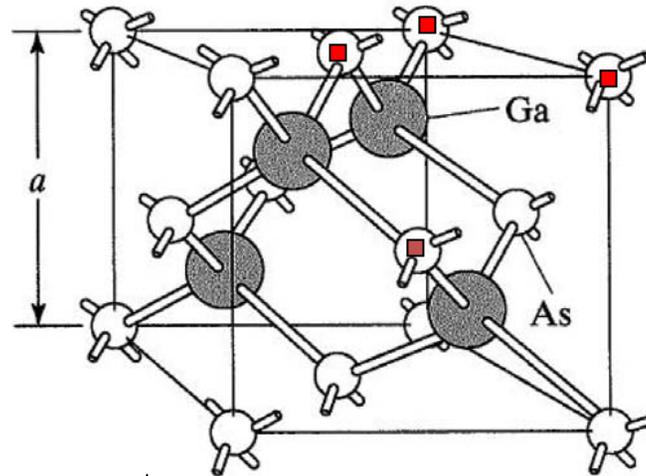
Atoms/cell = $(1/8) \times 8 + (1/2) \times 6 + 4 = 8$
FCC Lattice with a basis
Tetrahedral structure



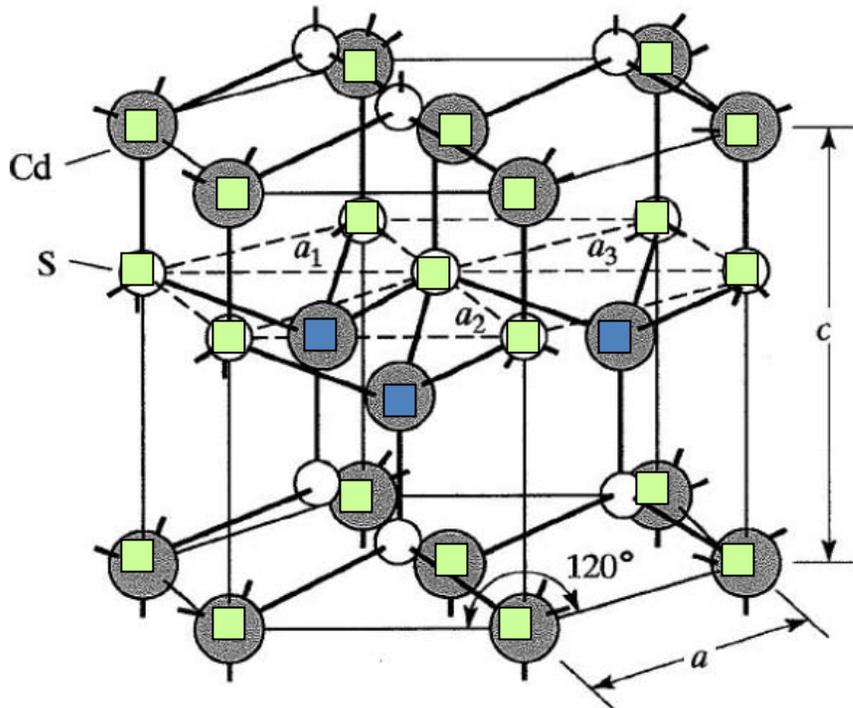
Diamond FCC Lattice for Silicon



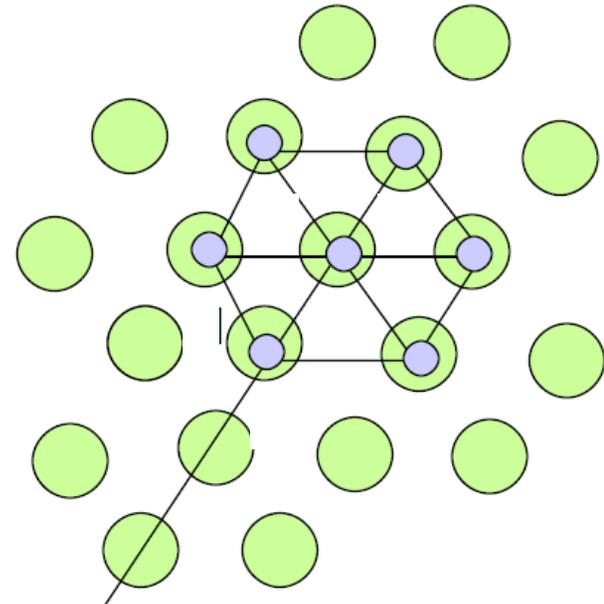
Surface Reconstruction



Hexagonal Closed-Packed for CdS



Focus on (Cd) ...

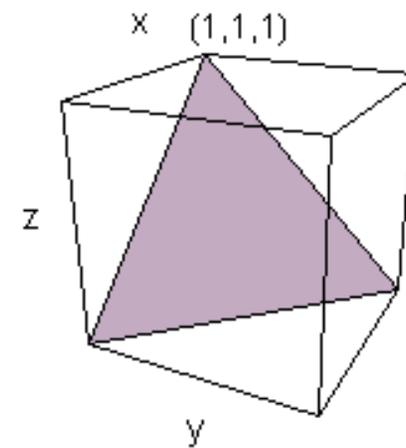
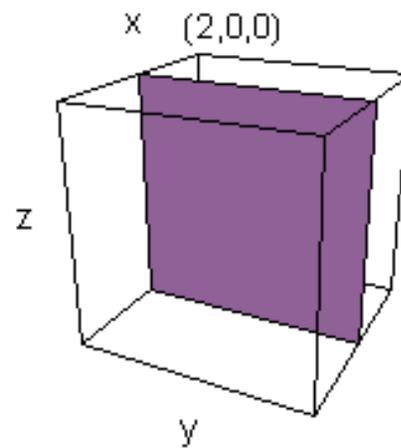
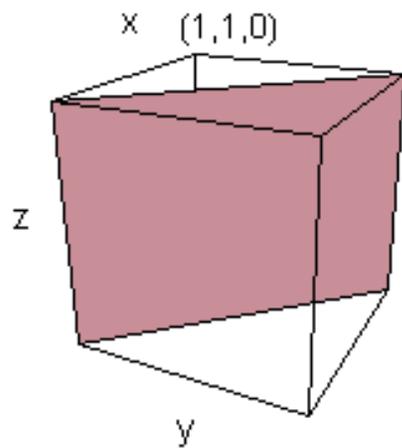
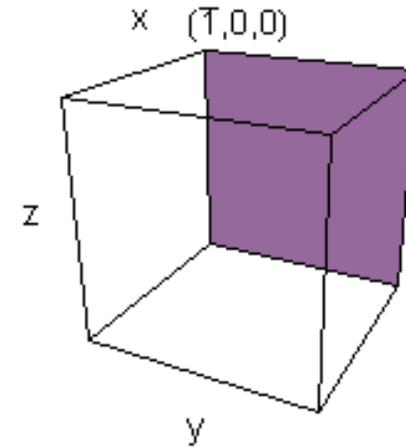
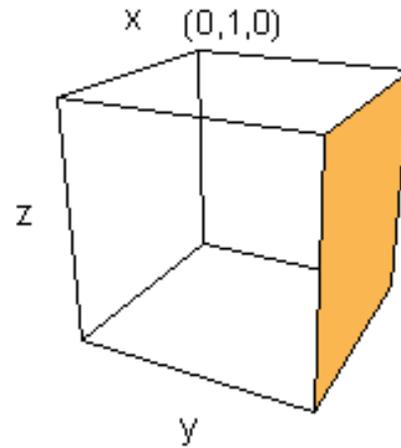
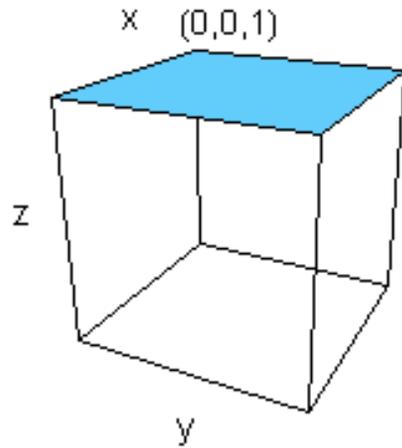


$$\begin{aligned} \text{(Cd) atoms/cell} = \\ (1/6) \times 12 + (1/2) \times 2 + 3 = 6 \end{aligned}$$

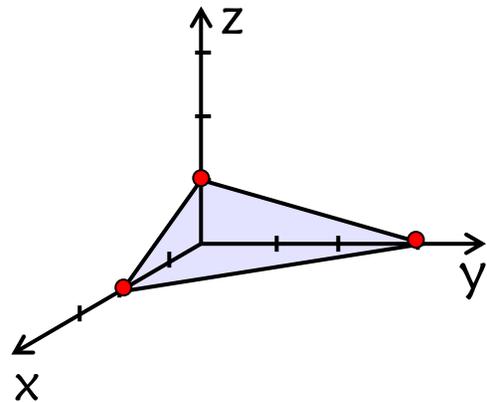
Outline

- 1) Volume & surface issues for BCC, FCC, Cubic lattices
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- 3) Miller indices**
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Miller-Indices and Definition of Planes



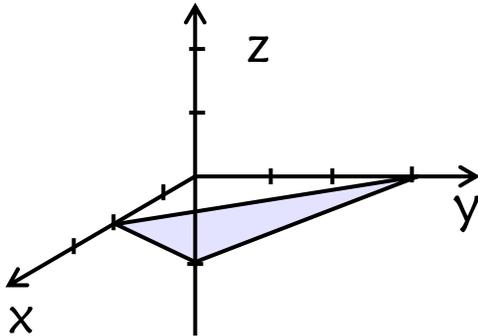
Miller Indices: Rules



1. Set up axes along the edges of unit cell
2. Normalize intercepts 2, 3, 1
3. Invert/rationalize intercepts ... 1/2, 1/3, 1
3/6, 2/6, 6/6
4. Enclose the numbers in curvilinear brackets
(326)

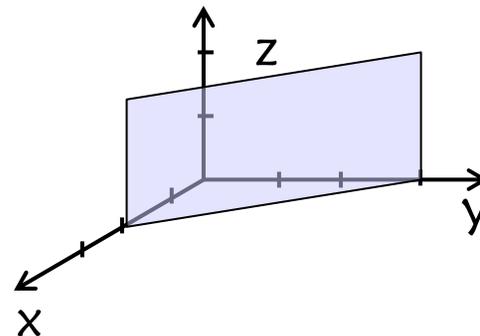
Few more rules ...

Negative Intercept



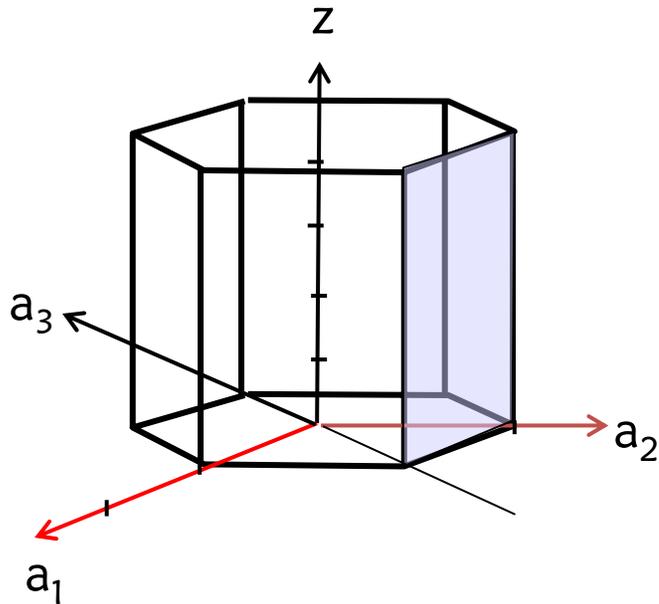
2,	3,	-2
1/2,	1/3,	-1/2
3,	2,	-3
(3	2	3)

Intercept at infinity



2,	3,	∞
1/2,	1/3,	0
3,	2,	0
(3	2	0)

Bravais-Miller Indices

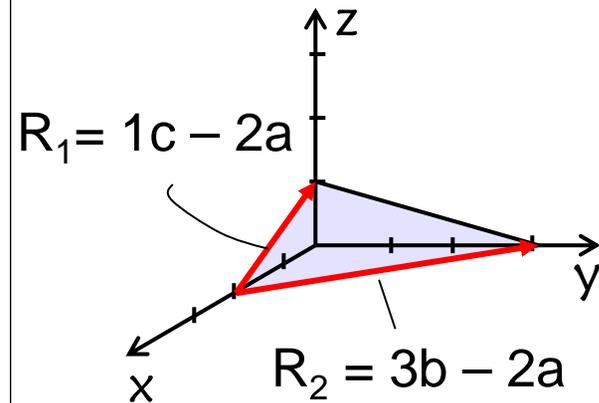


∞	1	-1	∞
0	1	-1	0
0	1	-1	0
$(0 \ 1 \ \bar{1} \ 0)$			

First three indices sum to zero.

Where does Miller Indices come from ?

Miller indices: (326)



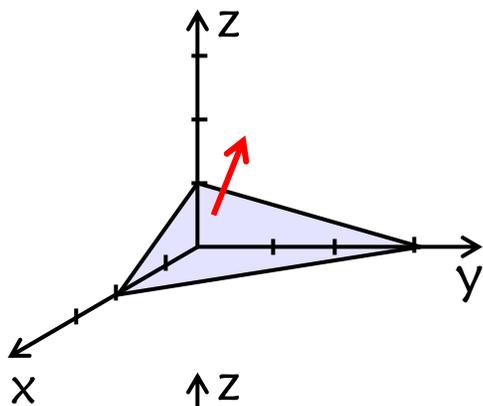
Normal to the surface

$$R_2 \times R_1 = \begin{vmatrix} a & b & c \\ -2 & 3 & 0 \\ -2 & 0 & 1 \end{vmatrix} = 3a + 2b + 6c$$

Vector indices same as Miller indices !

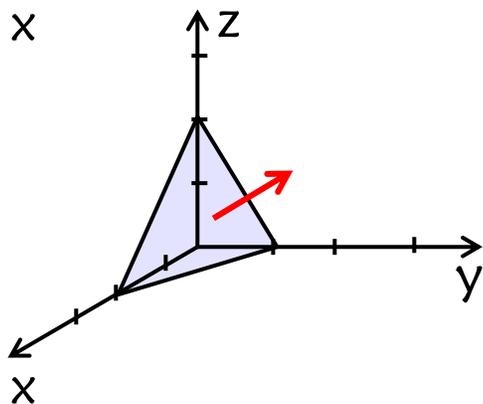
(326) vs. [326]

Angle between Two Planes



Unit vector normal to plane 1:

$$N_1 = (h_1 \vec{a} + k_1 \vec{b} + l_1 \vec{c}) / (h_1^2 + k_1^2 + l_1^2)^{1/2}$$



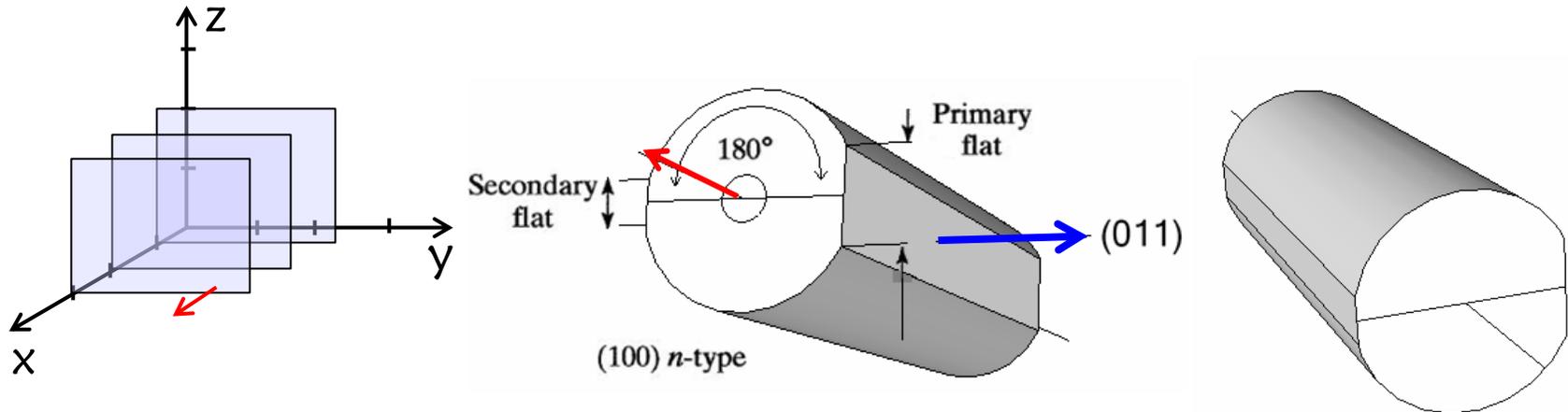
Unit vector normal to plane 2:

$$N_2 = (h_2 \vec{a} + k_2 \vec{b} + l_2 \vec{c}) / (h_2^2 + k_2^2 + l_2^2)^{1/2}$$

$$\cos(\theta) = N_1 \cdot N_2$$

$$= (h_2 h_1 + k_2 k_1 + l_2 l_1) / (h_2^2 + k_2^2 + l_2^2)^{1/2} (h_1^2 + k_1^2 + l_1^2)^{1/2}$$

Examples ...

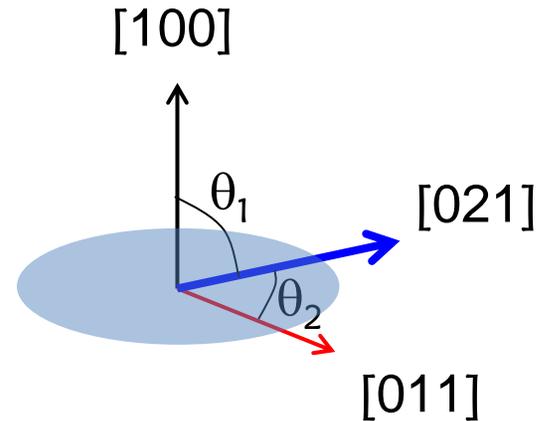
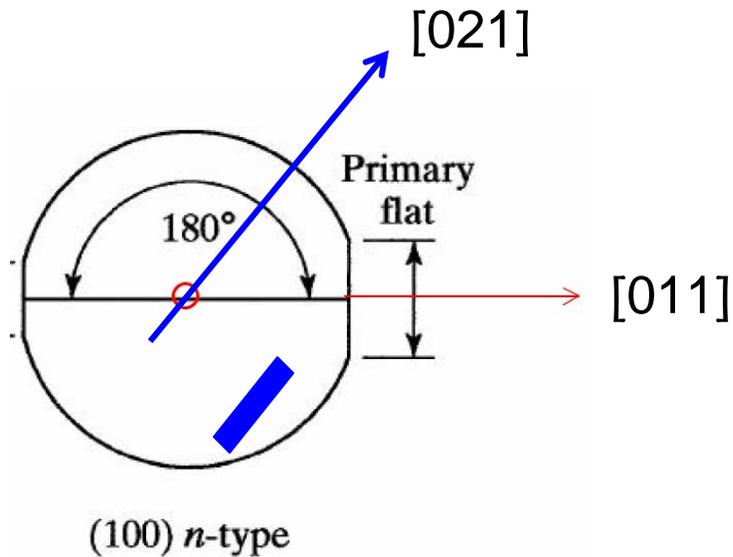


$$\cos(\theta) = (1 \times 0 + 0 \times 1 + 0 \times 1) / (\sqrt{1} \times \sqrt{2}) = 0$$

so $\theta = 90$ degrees

(011) surface is normal to (100) surface

Example use of Miller Indices .. Find [021] Direction



$$\cos(\theta_1) = \frac{\overset{\downarrow}{1} \times \overset{\downarrow}{0} + \overset{\downarrow}{0} \times \overset{\downarrow}{2} + \overset{\downarrow}{0} \times \overset{\downarrow}{1}}{1 \times \sqrt{5}} = 0, \text{ so } \theta_1 = 90 \text{ degrees}$$

[021] vector lies on (100) plane.

$$\cos(\theta_2) = \frac{\overset{\downarrow}{0} \times \overset{\downarrow}{0} + \overset{\downarrow}{2} \times \overset{\downarrow}{1} + \overset{\downarrow}{1} \times \overset{\downarrow}{1}}{\sqrt{5} \sqrt{2}}, \text{ so } \theta_2 = 18.5 \text{ degrees with respect to } [011] \text{ direction.}$$

Conclusions

1. To understand transport in semiconductors, we need to know carrier density (n) and carrier velocity (v). In order to find these quantities, we need to understand the chemical composition and atomic arrangements.
2. Crystalline material can be built by repeating the basic building blocks. This simplifies the quantum solution of the material, which will allow us to compute n and v for these systems easily.
3. Silicon, GaAs, PbS do not have simple Bravais lattice; but they have Bravais lattice with basis.
4. Often we need to calculate the direction of crystal planes because material properties differ along different planes. Miller indices are one useful way of characterizing crystal planes. It is useful to review some identities of vector calculus to such calculations involving crystal planes.

Looking ahead

Number of atoms/volume
from crystal structure

Number of electrons
available for conduction

Number of electrons/atoms

$$n \neq \rho \times N$$

II	III	IV	V	VI
4 Be	5 B	6 C	7 N	8 O
12 Mg	13 Al	14 Si	15 P	16 S
30 Zn	31 Ga	32 Ge	33 As	34 Se
48 Cd	49 In	50 Sn	51 Sb	52 Te
80 Hg	81 Tl	82 Pb	83 Bi	84 Po

All electrons may be created equally,
but they appear do not behave identically!